阅读申明

- 1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任何异议请及时告之,我们将妥善解决。
- 2.本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
- 3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。
- 4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

- 1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
- 2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
- 3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
- 4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

HTZ170C Series

 $I_{F(AV)} = 10 A$

 $V_{RRM} = 2800 V$

High Voltage Diode Rectifier Module

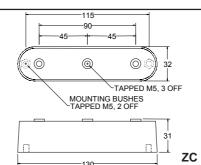
LARONTROLElectronic Devices

Type Number	Repetitive Peak	Minimum Avalanche Voltage V _{(BR)R}			
HTZ170C2.8K HTZ170C2.4K HTZ170C2K	2800 2400 2000	3000 2600 2200	ON O EO		
CIRCUIT DIAGRA	÷	tre Tap			
			Half wave resistive load $T_{amb} = 35^{\circ}C$ $T_{amb} = 35^{\circ}C$	10 10.8 7	A A °C/W
			Half wave resistive load $T_{oil} = 60^{\circ}C$ $T_{oil} = 60^{\circ}C$	21.5 23.5 2.5	
SURGE RATINGS I²t			10 ms half sine T_{v_j} = 150°C T_{v_j} = 150°C	5000 1000	A²sec A
T_{vj} Virt T_{stg} Sto	E AND FREQUENCE ual junction temper rage temperature re quency range	rature	Forward (conducting) Reverse (blocking)	180 180 -40 to 100 20 to 400	°C °C Hz
CHARACTERIS V _{FM} For		C unless otherwis	e stated At 40 Amps peak At V _{RRM} ; T _{case} = 150°C	max 1.9 max 0.5	

Dimensioned Outlines

Dimensions shown are maximum in mm

Weight typ.: 0,28 Kg



IXYS reserves the right to change limits, test conditions and dimensions

Distributed by USA 3540 Bassett Street Santa Clara, CA 95054 Phone: (408) 982-0700 FAX: (408) 496-0670

EUROPE IXYS Semiconductor GmbH Lampertheim Germany Phone: +49.6206.503.0 Fax: +49.6206.503.627



Issue 1 June 1998

HTZ170C Series

 $I_{F(AV)} = 10 \text{ A}$ $V_{RRM} = 2800 \text{ V}$

High Voltage Diode Rectifier Module

LARONTROL

Electronic Devices

